

# NCE P-Channel Enhancement Mode Power MOSFET

#### **DESCRIPTION**

The NCE3407A uses advanced trench technology to provide excellent  $R_{\rm DS(ON)}$ , low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a load switch or in PWM applications.

#### **GENERAL FEATURES**

•  $V_{DS} = -30V, I_{D} = -4.3A$ 

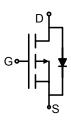
 $R_{DS(ON)}$  < 85m $\Omega$  @  $V_{GS}$ =-4.5V

 $R_{DS(ON)}$  <60m $\Omega$  @  $V_{GS}$ =-10V

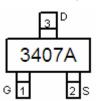
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

# **Application**

- ●PWM applications
- Load switch
- Power management



#### Schematic diagram



#### Marking and pin Assignment



SOT-23 top view

#### **Package Marking And Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3407A	NCE3407A	SOT-23	Ø180mm	8 mm	3000 units

#### Absolute Maximum Ratings (TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-30	V
Gate-Source Voltage	V <sub>GS</sub>	±20	V
Drain Current-Continuous	I <sub>D</sub>	-4.3	Α
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	-20	Α
Maximum Power Dissipation	P <sub>D</sub>	1.5	W
Operating Junction and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 To 150	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2) R <sub>BJA</sub> 84 °C/W
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#### Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-30	-33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-24V,V <sub>GS</sub> =0V	-	-	-1	μA



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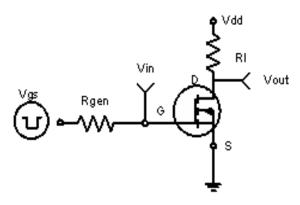
# **NCE3407A**

Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	·					
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-1	-1.5	-3	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-4.1A	-	50	60	mΩ
Diain-Source On-State Resistance		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4A	-	67	85	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4.1A	5.5	-	-	S
Dynamic Characteristics (Note4)	·					
Input Capacitance	C <sub>lss</sub>	\/ - 45\/\/ -0\/	-	700	-	PF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =-15V, $V_{GS}$ =0V, F=1.0MHz	-	120	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	r = 1.0ivii 12	-	75	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	9	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-15V, $R_{L}$ =3.6 $\Omega$	-	5	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =-10 $V$ , $R_{GEN}$ =3 $\Omega$	-	28	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	13.5	-	nS
Total Gate Charge	$Q_g$		-	14	-	nC
Gate-Source Charge	$Q_{gs}$	V <sub>DS</sub> =-15V,I <sub>D</sub> =-4A,V <sub>GS</sub> =-10V	-	3.1	-	nC
Gate-Drain Charge	Q <sub>gd</sub>		-	3.	-	nC
<b>Drain-Source Diode Characteristics</b>						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-1A	-	-	-1.2	V
		•				

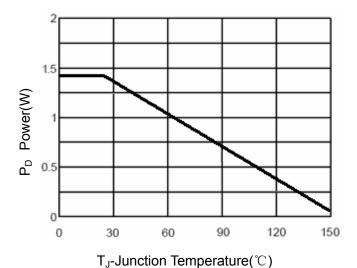
# Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width  $\leq$  300 $\mu$ s, Duty Cycle  $\leq$  2%.
- 4. Guaranteed by design, not subject to production

# TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

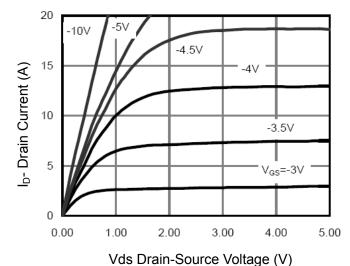


Figure 5 Output CHARACTERISTICS

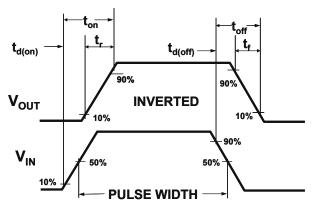
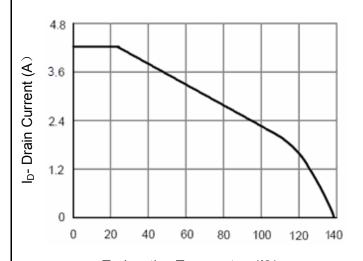


Figure 2:Switching Waveforms



T<sub>J</sub>-Junction Temperature(°C)

Figure 4 Drain Current

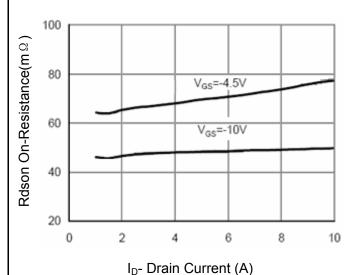
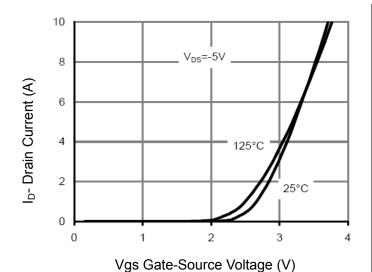
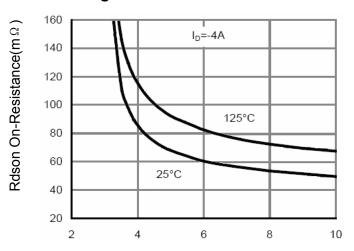


Figure 6 Drain-Source On-Resistance





**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)

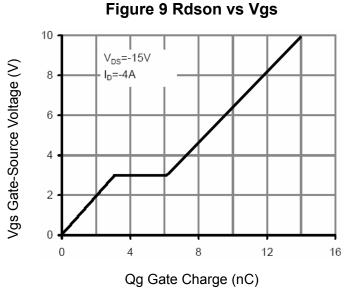


Figure 11 Gate Charge

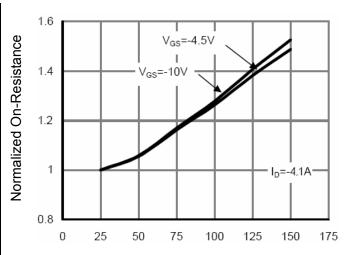
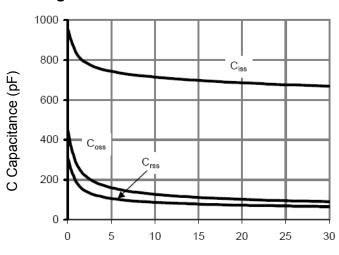


Figure 8 Drain-Source On-Resistance

 $T_J$ -Junction Temperature( $^{\circ}$ C)



Vds Drain-Source Voltage (V)

Figure 10 Capacitance vs Vds

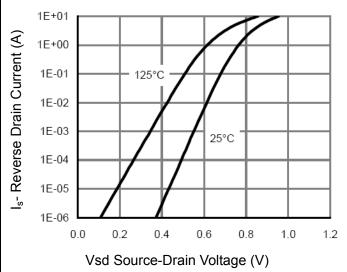


Figure 12 Source- Drain Diode Forward

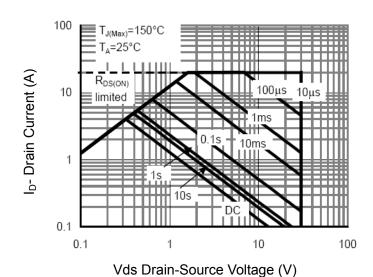
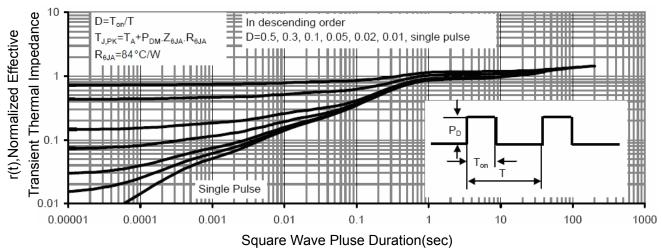


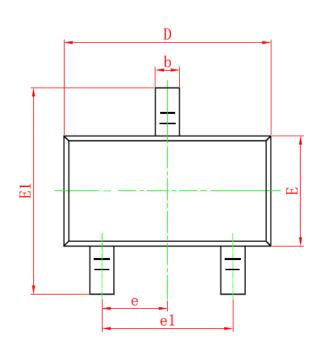
Figure 13 Safe Operation Area

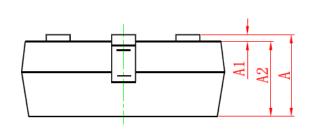


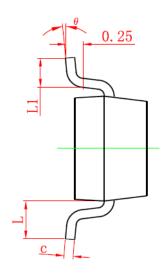
**Figure 14 Normalized Maximum Transient Thermal Impedance** 

# **SOT-23 PACKAGE INFORMATION**

# **Dimensions in Millimeters (UNIT:mm)**







Symbol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
Α	0.900	1.150		
<b>A</b> 1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

#### **NOTES**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$

**NCE3407A** 

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